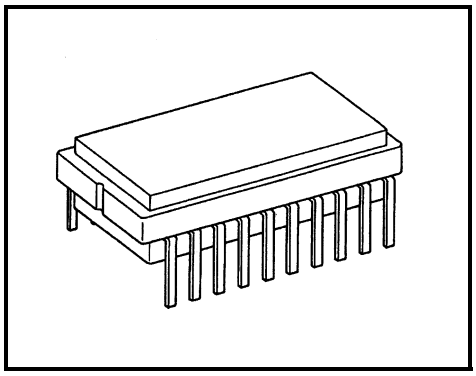
TOSHIBA CCD LINEAR IMAGE SENSOR CCD(Charge Coupled Device)

TCD1001P

The TCD1001P is a high sensitive and low dark current 128−elements linear image sensor which includes CCD drive circuit, clamp circuit and sample & hold circuit.
The CCD drive circuit consists of the pulse generator therefore it is possible to easy drive by applying simple pulses. The sensor is designed for scanner.



Weight: 1.0g (typ.)

FEATURES

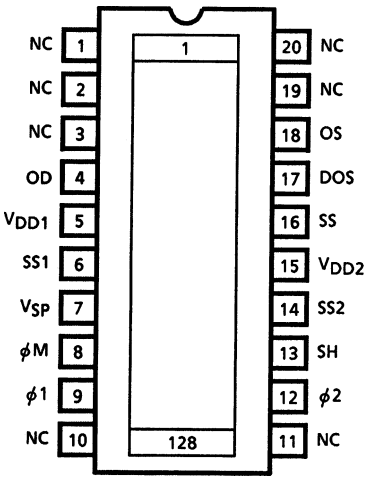
- Number of Image Sensing Elements : 128 elements
- Image Sensing Element Size : 32μm×32μm on 32μm centers
- Photo Sensing Region : High sensitive pn photodiode
- Clock : 3 Input pulses 5V
- Internal Circuit : Sample & Hold circuit, Clamp circuit
- Package : 20 pin

MAXIMUM RATINGS

CHARACTERISTICS	SYMBOL	RATING	UNIT
Master Clock Voltage	$V_{\varphi M}$	−0.3~8	V
Clock Pulse Voltage	V_{φ}		
Shift Pulse Voltage	V_{SH}		
Power Supply Voltage (Analog)	V_{AD}	−0.3~15	V
Power Supply Voltage (Digital)	V_{DD1}		
	V_{DD2}		
Sample & Hold Switch Voltage	V_{SP}	−0.3~15	V
Operating Temperature	T_{opr}	0~60	°C
Storage Temperature	T_{stg}	−25~85	°C

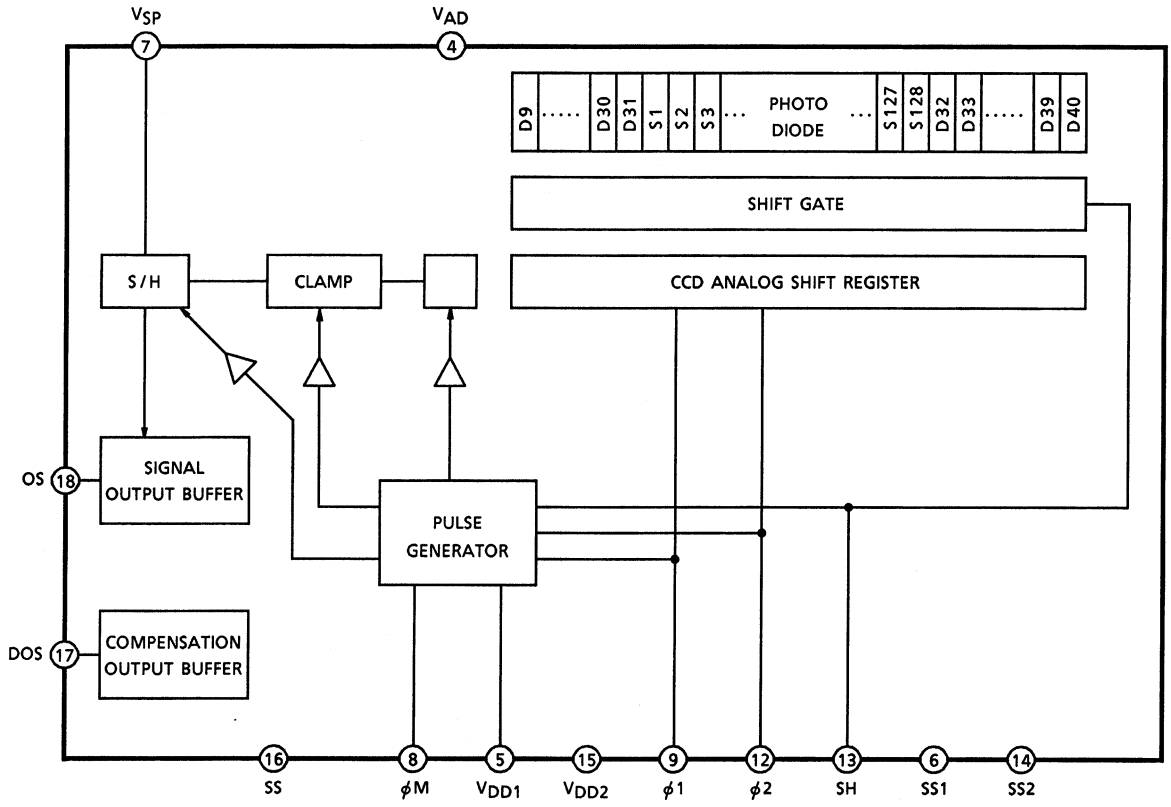
Note 1: All voltage are with respect to SS terminals(Ground).

PIN CONNECTION



(TOP VIEW)

CIRCUIT DIAGRAM



PIN NAMES

φ_M	Master Clock	V_{AD}	Power (Analog)
φ_1	Clock (Phase 1)	V_{DD1}	Power (Digital, 12V)
φ_2	Clock (Phase 2)	V_{DD2}	Power (Digital, 12V)
SH	Shift Gate	SS	Ground (Analog)
OS	Signal Output	SS1	Ground (Digital, 12V)
DOS	Compensation Output	SS2	Ground (Digital, 12V)
NC	Non Connection	V_{SP}	Sample and Hold Switch

OPTICAL / ELECTRICAL CHARACTERISTICS

(Ta = 25°C, V_{AD} = V_{DD1} = V_{DD2} = 12V, $V_{\varphi M}$ = V_{φ} = V_{SH} = 5V (PULSE), f_{φ} = 1.0MHz, t_{INT} (INTEGRATION TIME) = 10ms, LIGHT SOURCE = DAYLIGHT FLUORESCENT LAMP, LOAD RESISTANCE = 100kΩ)

CHARACTERISTICS	SYMBOL	MIN	TYP.	MAX	UNIT	NOTE
Sensitivity	R	63.7	85	106	V / lx·s	
Photo Response Non Uniformity	PRNU (1)	—	—	10	%	(Note 2)
	PRNU (3)	—	3	12	mV	(Note 3)
Saturation Output Voltage	V_{SAT}	1.2	2.0	—	V	(Note 4)
Saturation Exposure	SE	—	0.02	—	lx·s	(Note 5)
Dark Signal Voltage	V_{DRK}	—	4	8	mV	(Note 6)
Dark Signal Non Uniformity	D_{SNU}	—	2	5	mV	(Note 6)
Analog Current Dissipation	I_{AD}	—	8.0	12	mA	
Digital Current Dissipation	I_{DD1}	—	—	1	mA	
	I_{DD2}	—	10.0	15	mA	
Total Transfer Efficiency	TTE	92	—	—	%	
Output Impedance	Z_O	—	0.5	1.0	kΩ	
DC Signal Output Voltage	V_{OS}	3.5	5.0	6.5	V	(Note 7)
DC Compensation Output Voltage	V_{DOS}	3.5	5.0	6.5	V	(Note 7)
DC Differential Error Voltage	$\lvert V_{OS}-V_{DOS}\rvert$	—	—	400	mV	

Note 2: PRNU (1) is measured at 50% of SE (Typ.)

Definition of PRNU : PRNU = $\frac{\Delta\chi}{\bar{\chi}} \times 100(\%)$

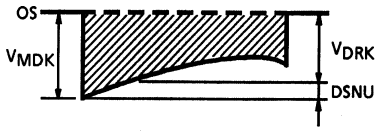
Where $\bar{\chi}$ is average of total signal outputs and $\Delta\chi$ is the maximum deviation from $\bar{\chi}$ under uniform illumination.

Note 3: PRNU (3) is defined as maximum voltage with next pixel where measured 5% of SE (Typ.)

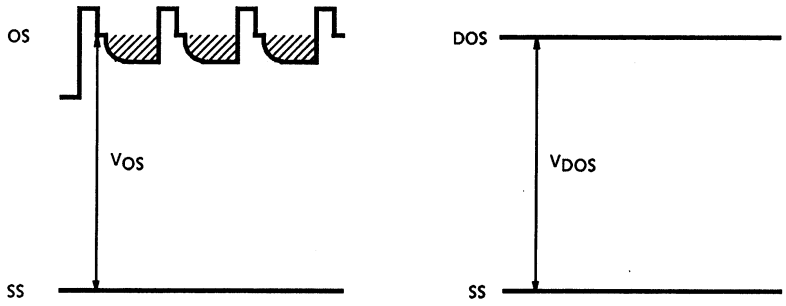
Note 4: V_{SAT} is defined as minimum Saturation Output Voltage of all effective pixels.

Note 5: Definition of SE : SE = $\frac{V_{SAT}}{R}(lx \cdot s)$

Note 6: V_{DRK} is defined as average dark signal voltage of all effective pixels.
DSNU is defined as different voltage between V_{DRK} and V_{MDK} when V_{MDK} is maximum dark signal voltage.



Note 7: DC signal output voltage and DC compensation output voltage are defined as follows:



OPERATING CONDITION

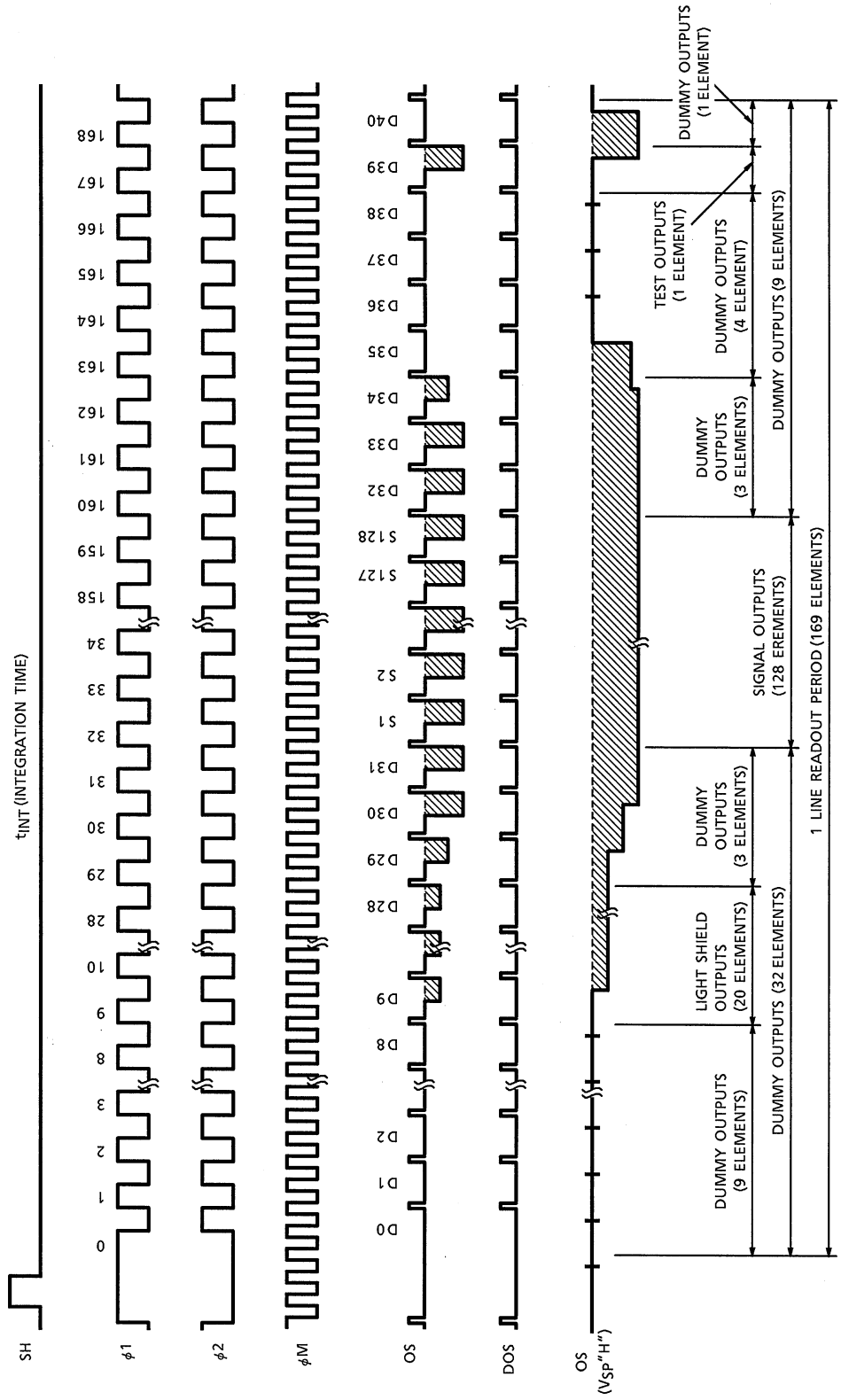
CHARACTERISTICS		SYMBOL	MIN	TYP.	MAX	UNIT
Master Clock Pulse Voltage	"H" Level	$V_{\varphi M}$	4.5	5.0	5.5	V
	"L" Level		0	—	0.5	
Clock Pulse Voltage	"H" Level	$V_{\varphi 1}$	4.5	5.0	5.5	V
	"L" Level	$V_{\varphi 2}$	0	—	0.5	
Shift Pulse Voltage	"H" Level	V_{SH}	$V_{\varphi}-0.5$	V_{φ}	V_{φ}	V
	"L" Level		0	—	0.5	
Sample and Hold Switch Voltage*	"H" Level	V_{SP}	4.5	5.0	13.0	V
	"L" Level		0	—	0.5	
Power Supply Voltage (Analog)		V_{AD}	11.4	12.0	13.0	V
Power Supply Voltage (Digital)		V_{DD1}	11.4	12.0	13.0	V
		V_{DD2}	11.4	12.0	13.0	

*: Supply "H" Level to V_{SP} terminal when sample−and−hold circuit is used, when sample−and−hold circuit is not used supply "L" Level to V_{SP} terminal.

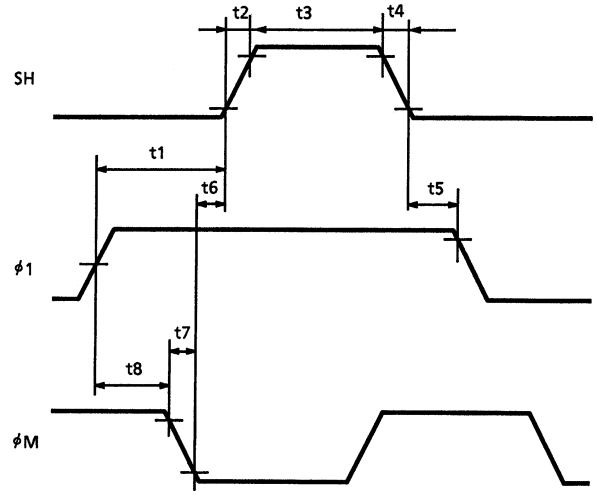
CLOCK CHARACTERISTICS (Ta = 25°C)

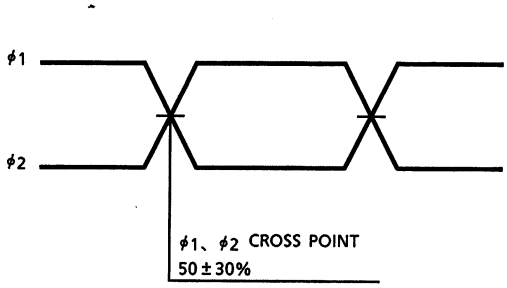
CHARACTERISTICS	SYMBOL	MIN	TYP.	MAX	UNIT
Master Clock Pulse Frequency	$f_{\varphi M}$	—	2.0	6.0	MHz
Clock Pulse Frequency	f_{φ}	—	1.0	3.0	MHz
Master Clock Pulse Capacitance	$C_{\varphi M}$	—	10	20	pF
Clock Capacitance	C_{φ}	—	100	200	pF
Shift Gate Capacitance	C_{SH}	—	50	100	pF

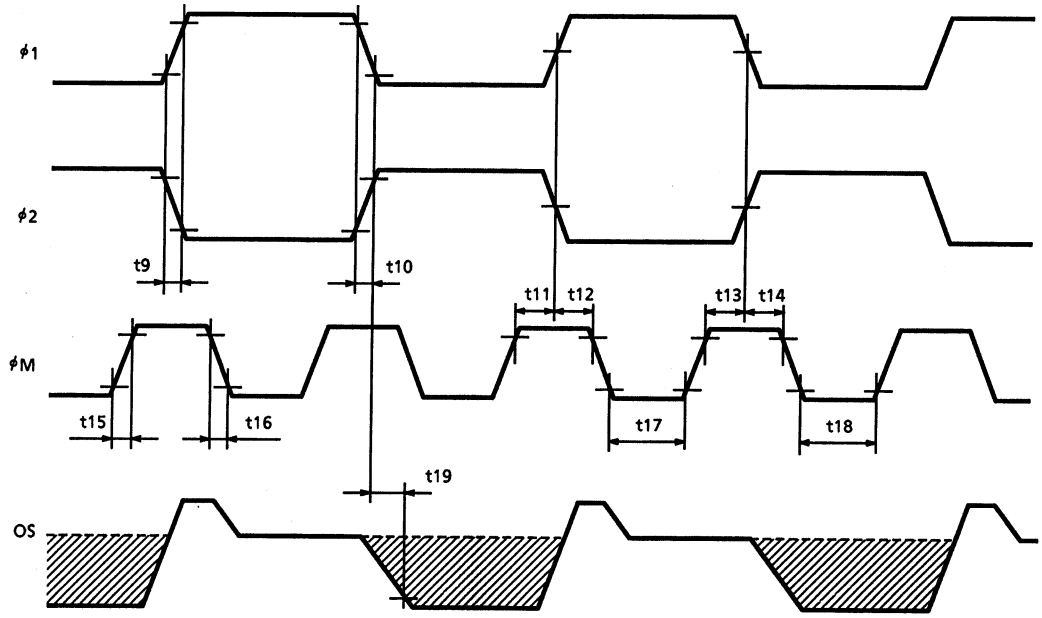
TIMING CHART

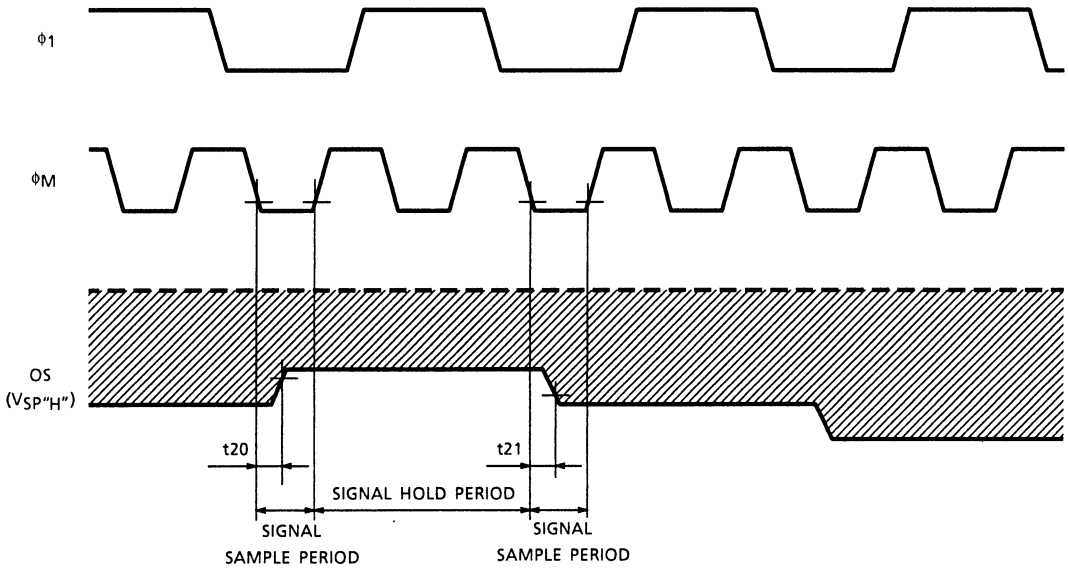


TIMING REQUIREMENS





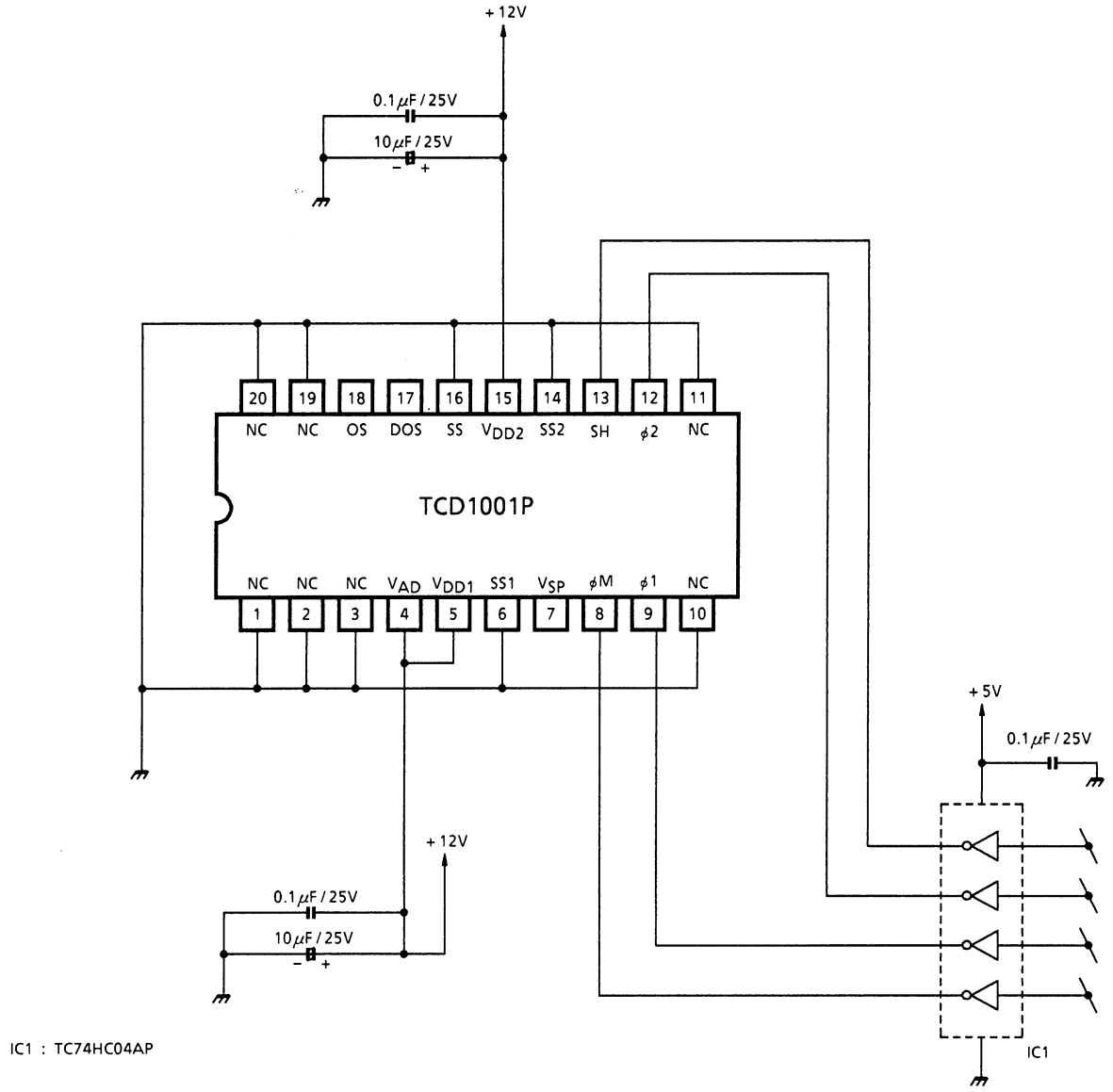




CHARACTERISTICS	SYMBOL	MIN	TYP. (Note 2)	MAX	UNIT
Pulse Timing of SH and φ_1, φ_2	t1	60	300	—	ns
	t5	0	300	—	ns
SH Pulse Rise Time, Fall Time	t2, t4	0	50	—	ns
SH Pulse Width	t3	300	1000	—	ns
Pulse Timing of SH and Φ_M	t6	20	50	—	ns
φ_1, φ_2 Pulse Rise Time, Fall Time	t9, t10	0	20	—	ns
Pulse Timing of φ_1, φ_2 and φ_M	t11, t13	20	100	—	ns
	t8, t12, t14	40	100	—	ns
φ_M Pulse Rise Time, Fall Time	t7, t15, t16	0	20	—	ns
φ_M Pulse Width	t17, t18	80	250	—	ns
Video Data Delay Time (Note 3)	t19	—	45	—	ns
S / H Video Data Delay Time	t20, t21	—	70	—	ns

Note 2: TYP. is the case of f_φ = 1MHz.
Note 3: Load Resistance is 100kΩ.

TYPICAL DRIVE CIRCUIT



IC1 : TC74HC04AP

CAUTION

1. Window Glass

The dust and stain on the glass window of the package degrade optical performance of CCD sensor.

Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N2. Care should be taken to avoid mechanical or thermal shock because the glass window is easily to damage.

2. Electrostatic Breakdown

Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

CCD Image Sensor is protected against static electricity, but interior puncture mode device due to static electricity is sometimes detected. In handing the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.
b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.
c. Ground the tools such as soldering iron, radio cutting pliers of or pincer.

It is not necessarily required to execute all precaution items for static electricity.

It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.

3. Incident Light

CCD sensor is sensitive to infrared light. Note that infrared light component degrades resolution and PRNU of CCD sensor.

4. Lead Frame Forming

Since this package is not strong against mechanical stress, you should not reform the lead frame.

We recommend to use a IC-inserter when you assemble to PCB.

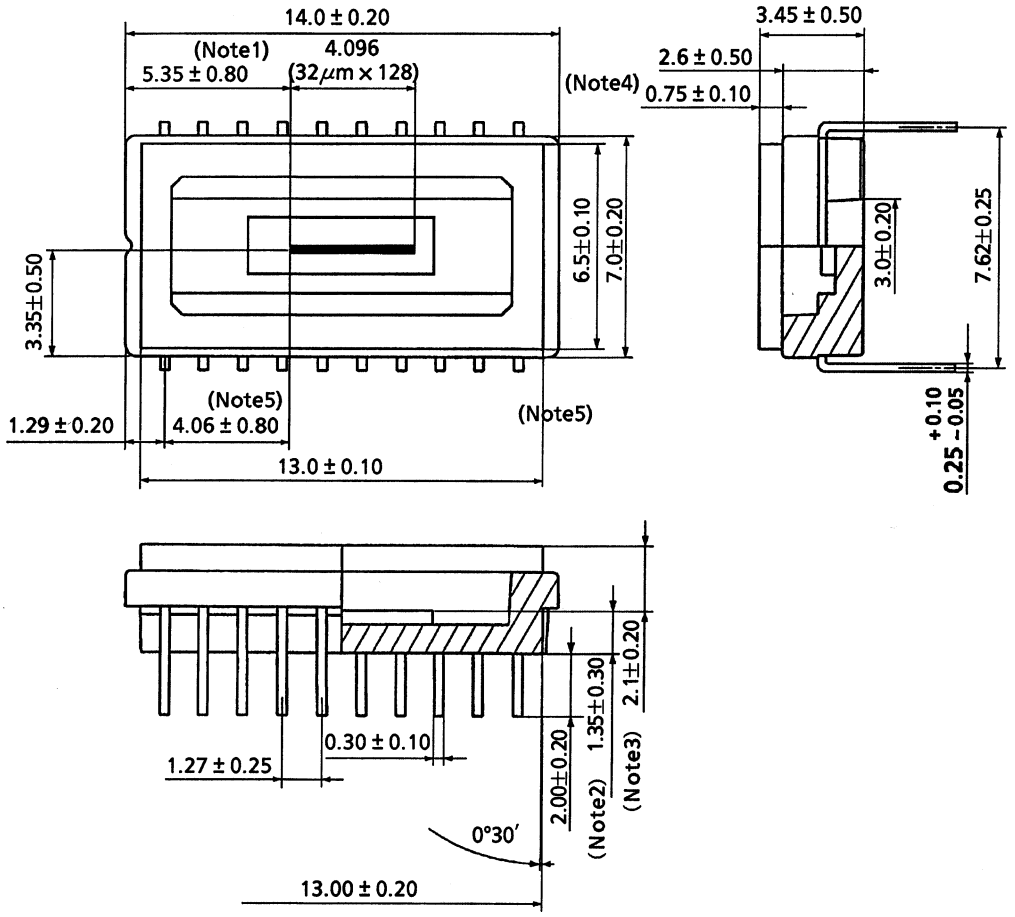
5. Soldering

Soldering by the solder flow method cannot be guaranteed because this method may have deleterious effects on prevention of window glass soiling and heat resistance.

Using a soldering iron, complete soldering within ten seconds for lead temperatures of up to 260°C, or within three seconds for lead temperatures of up to 350°C.

PACKAGE DIEMENSIONS

Unit : mm



Note1: No. 1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.
Note2: TOP OF CHIP TO BOTTOM OF PACKAGE.
Note3: TOP OF CHIP TO OF PACKAGE.
Note4: GLASS THICKNESS (n = 1.5)
Note5: No. 1 SENSOR ELEMENT (S1) TO CENTER OF No. 1 PIN.

Weight: 1.0g (typ.)

RESTRICTIONS ON PRODUCT USE

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